

### STANDARD DIODES

### ADD-A-pak™ GEN V Power Modules

#### Features

- High Voltage
- Industrial Standard Package
- Thick Al metal die and double stick bonding
- Thick copper baseplate
- UL E78996 approved
- 3500V<sub>RMS</sub> isolating voltage

#### Benefits

- Up to 1600V
- Full compatible TO-240AA
- High Surge capability
- Easy Mounting on heatsink
- Al<sub>2</sub>O<sub>3</sub> DBC insulator
- Heatsink grounded

60 A  
80 A

#### Mechanical Description

The Generation V of Add-A-pak module combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid Copper baseplate at the bottom side of the device. The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improve thermal spread.

The Generation V of AAP module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other IR modules.

#### Electrical Description

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

#### Major Ratings and Characteristics

Parameters	IRK.56	IRK.71	Units
$I_{F(AV)}$ @ 100°C	60	80	A
$I_{F(RMS)}$	94	126	A
$I_{FSM}$ @ 50Hz	1600	1790	A
@ 60Hz	1680	1870	A
$i^2t$ @ 50Hz	12.89	15.90	KA <sup>2</sup> s
@ 60Hz	11.76	14.53	KA <sup>2</sup> s
$i^2\sqrt{t}$	128.9	159	KA <sup>2</sup> √s
$V_{RRM}$ range	400 to 1600		V
$T_J$	-40 to 150		°C
$T_{STG}$	-40 to 150		°C



## IRK.56, .71 Series

Bulletin I27140 rev. E 10/02

International  
IR Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ 150°C mA
IRK.56/.71	04	400	500	10
	06	600	700	
	08	800	900	
	10	1000	1100	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

#### Forward Conduction

Parameter	IRK.56	IRK.71	Units	Conditions		
$I_{F(AV)}$ Max. average forward current @ Case temperature	60	80	A	180° conduction, half sine wave		
	100	100	°C			
$I_{F(AV)}$ Max. average forward current @ Case temperature	55	70	A	180° conduction, half sine wave		
	105	108	°C			
$I_{F(RMS)}$ Max. RMS forward current	94	126	A	DC @ 92°C case temperature		
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	1600	1790	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max.
	1680	1870		t = 8.3ms	reapplied	
	1350	1500		t = 10ms	100% $V_{RRM}$	
	1420	1570		t = 8.3ms	reapplied	
$I^2t$ Maximum $I^2t$ for fusing	12.89	15.90	KA <sup>2</sup> s	t = 10ms	No voltage	
	11.76	14.53		t = 8.3ms	reapplied	
	9.12	11.25		t = 10ms	100% $V_{RRM}$	
	8.32	10.23		t = 8.3ms	reapplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	128.9	159.0	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$ Low level value of threshold voltage	0.96	0.83	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$V_{F(TO)2}$ High level value of threshold voltage	1.03	0.92		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$r_{f1}$ Low level value of forward slope resistance	2.81	2.68	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$r_{f2}$ High level value of forward slope resistance	2.48	2.40		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.		
$V_{FM}$ Max. forward voltage drop	1.51	1.50	V	$I_{FM} = \pi \times I_{F(AV)}$ , $T_J = 25^\circ\text{C}$ , $t_p = 400\mu\text{s}$ square wave		

#### Blocking

Parameter	IRK.56	IRK.71	Units	Conditions
$I_{RRM}$ Max. peak reverse leakage current	10		mA	$T_J = 150^\circ\text{C}$
$V_{INS}$ RMS isolation voltage	3500 (1 sec)		V	50 Hz, circuit to base, all terminals shorted

**Thermal and Mechanical Specifications**

Parameter	IRK.56	IRK.71	Units	Conditions
T <sub>J</sub> Junction temperature range	-40 to 150		°C	
T <sub>stg</sub> Storage temperature range	-40 to 150		°C	
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.5	0.4	K/W	Per junction, DC operation
R <sub>thCS</sub> Typical thermal resistance, case to heatsink	0.1		K/W	Mounting surface flat, smooth and greased
T Mounting torque ±10% to heatsink busbar	5 4		Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
wt Approximate weight	110 (4)		gr (oz)	
Case style	TO-240AA			JEDEC

**ΔR Conduction (per Junction)**

(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Devices	Sine half wave conduction					Rect. wave conduction					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.56	0.11	0.13	0.16	0.22	0.32	0.09	0.14	0.17	0.23	0.32	°C/W
IRK.71	0.06	0.08	0.11	0.14	0.21	0.06	0.09	0.11	0.15	0.21	

**Ordering Information Table**

**Device Code**

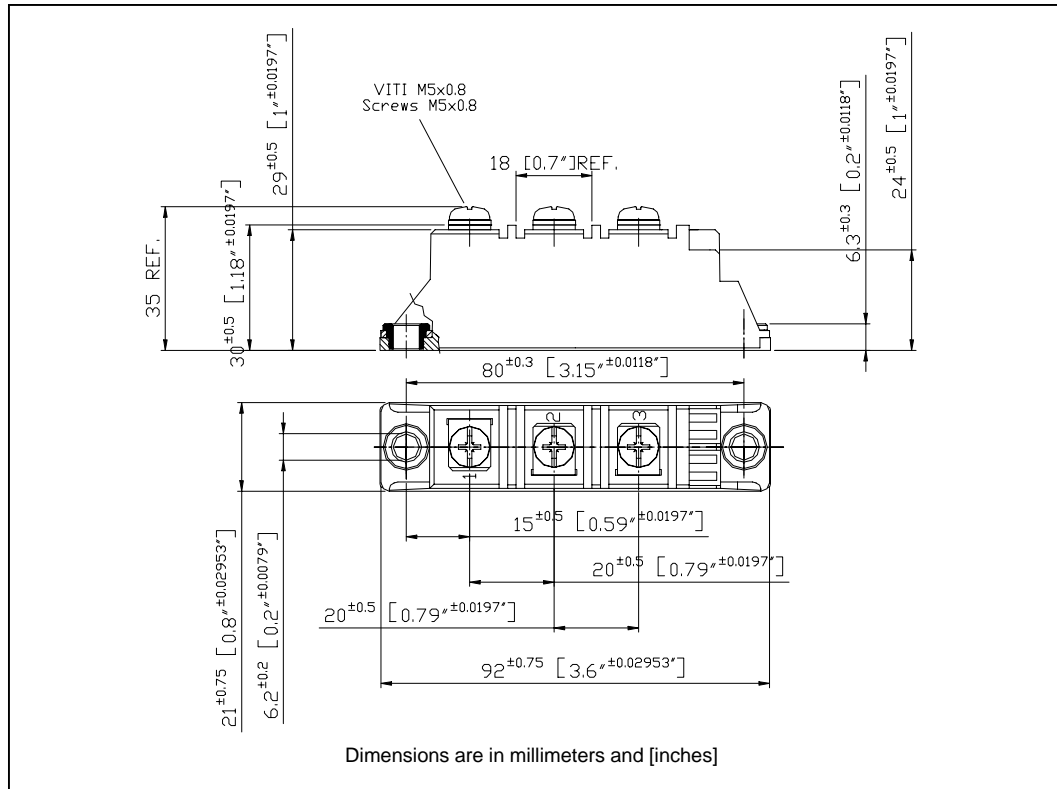
IRK	D	71	/	16	A
①	②	③		④	⑤

- 1** - Module type
- 2** - Circuit configuration (See Circuit Configuration Table)
- 3** - Current code
- 4** - Voltage code (See Voltage Ratings Table)
- 5** - A: Gen V

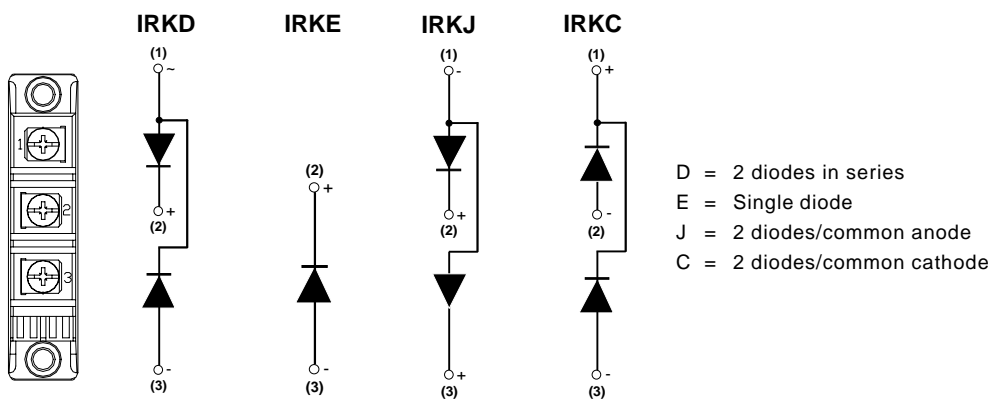
# IRK.56, .71 Series

Bulletin I27140 rev. E 10/02

## Outline Table



## Circuit Configuration Table



**NOTE: To order the Optional Hardware see Bulletin I27900**

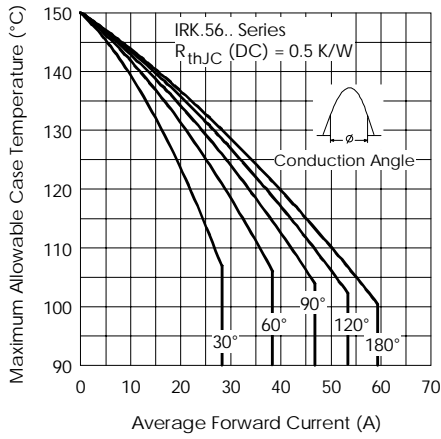


Fig. 1 - Current Ratings Characteristics

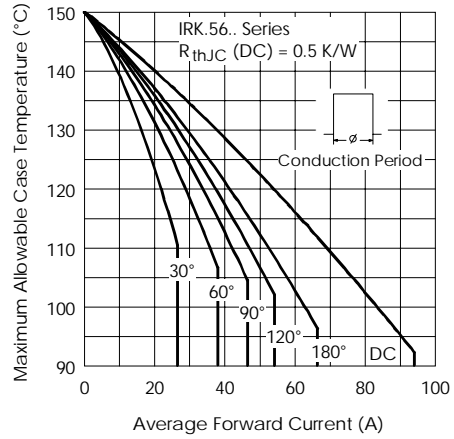


Fig. 2 - Current Ratings Characteristics

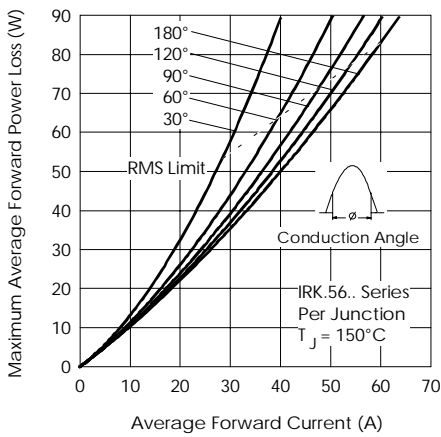


Fig. 3 - Forward Power Loss Characteristics

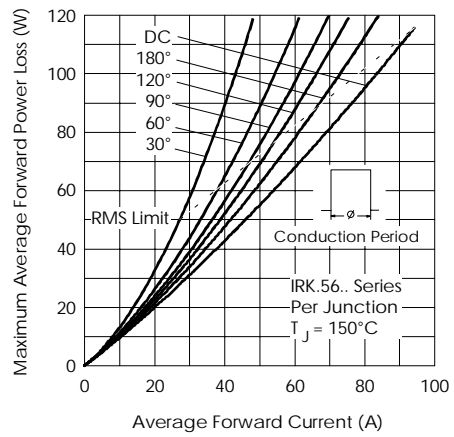


Fig. 4 - Forward Power Loss Characteristics

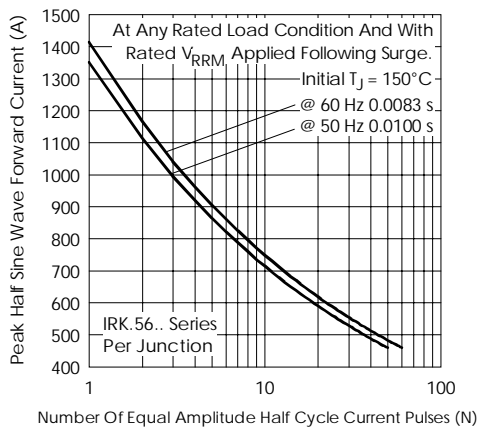


Fig. 5 - Maximum Non-Repetitive Surge Current

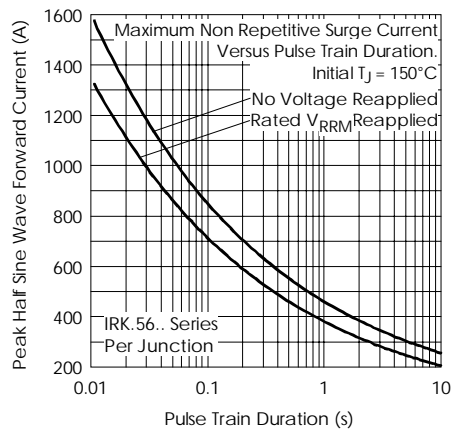


Fig. 6 - Maximum Non-Repetitive Surge Current

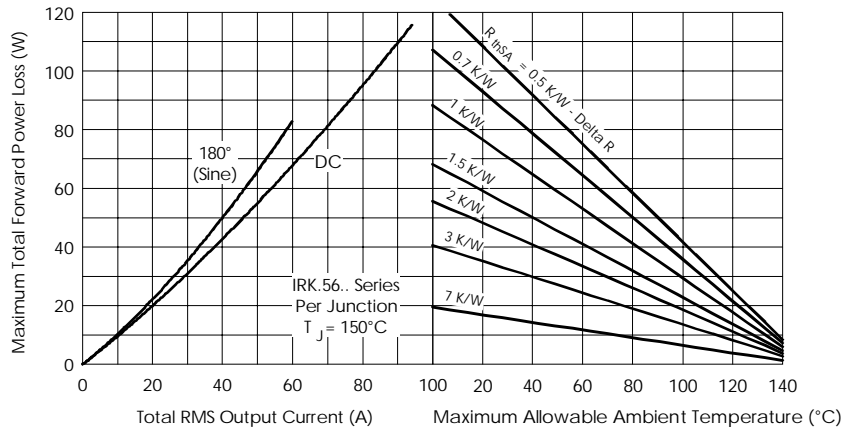


Fig. 7 - Forward Power Loss Characteristics

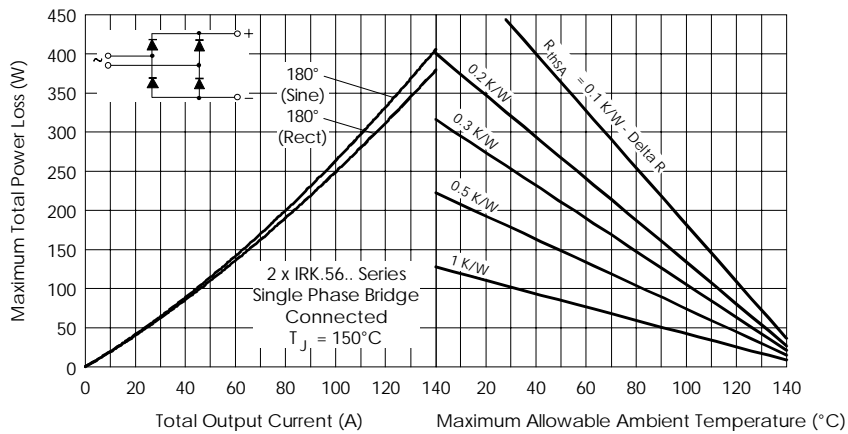


Fig. 8 - Forward Power Loss Characteristics

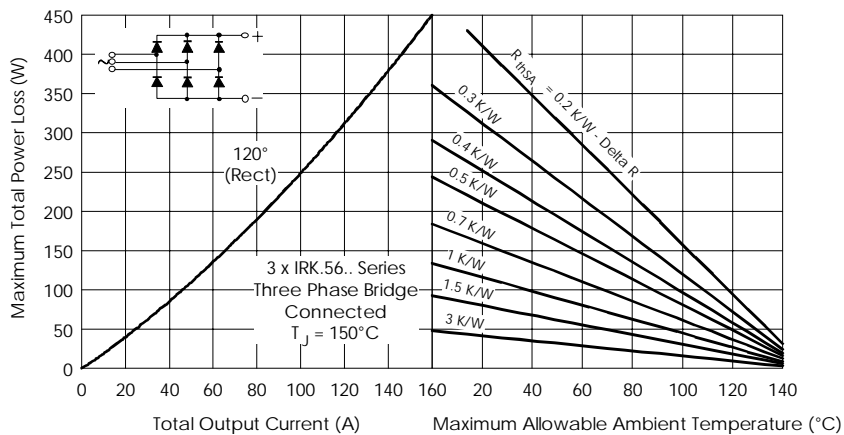


Fig. 9 - Forward Power Loss Characteristics

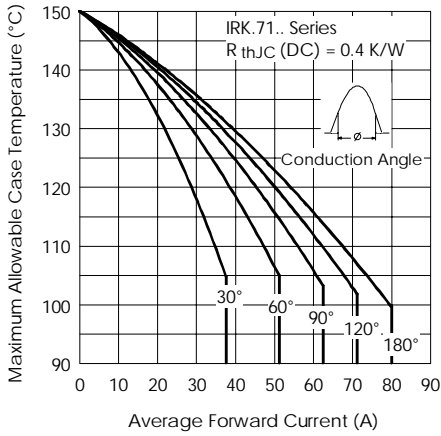


Fig. 10 - Current Ratings Characteristics

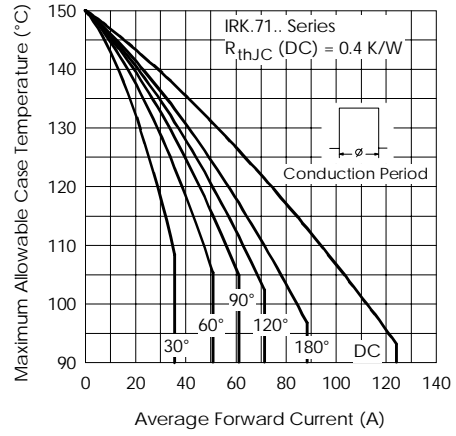


Fig. 11 - Current Ratings Characteristics

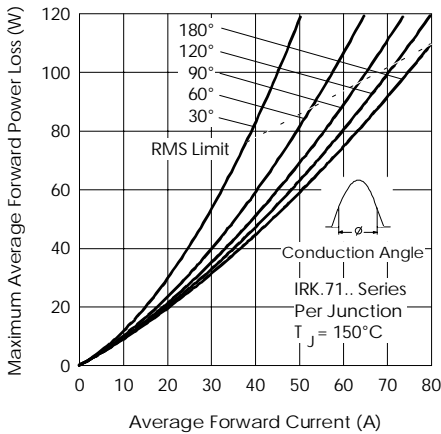


Fig. 12 - Forward Power Loss Characteristics

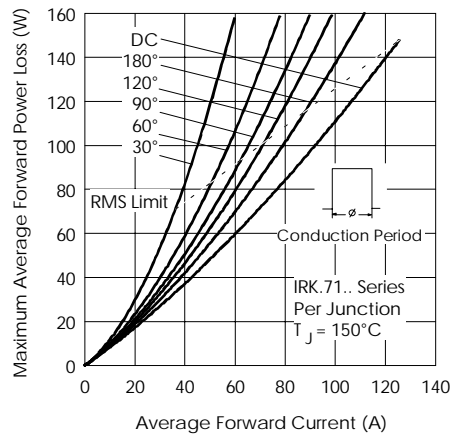


Fig. 13 - Forward Power Loss Characteristics

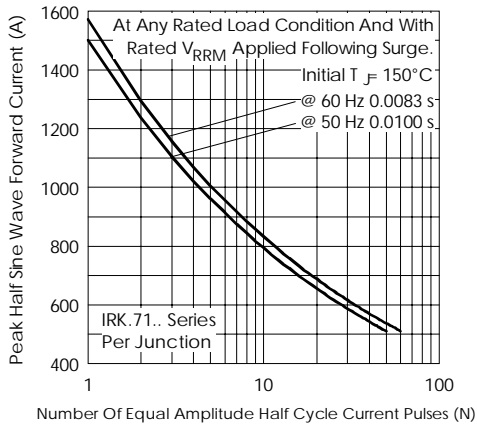


Fig. 14 - Maximum Non-Repetitive Surge Current

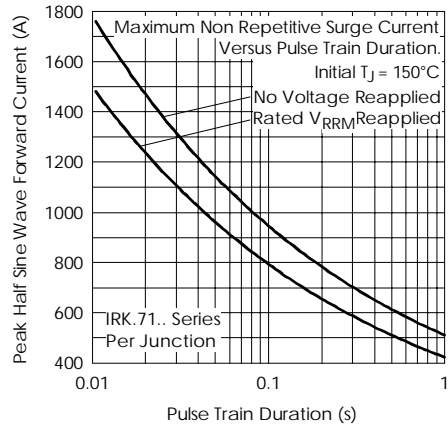


Fig. 15 - Maximum Non-Repetitive Surge Current

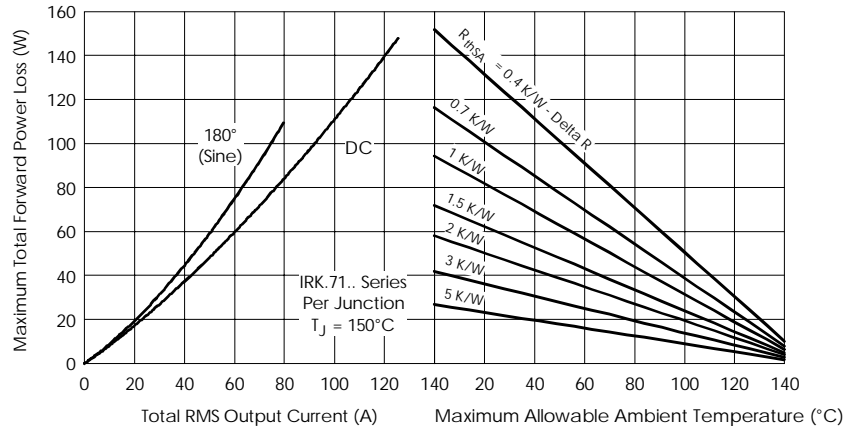


Fig. 16 - Forward Power Loss Characteristics

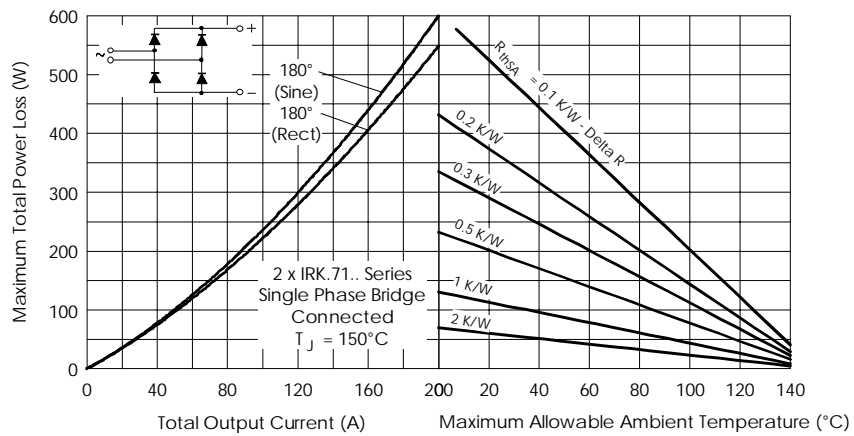


Fig. 17 - Forward Power Loss Characteristics

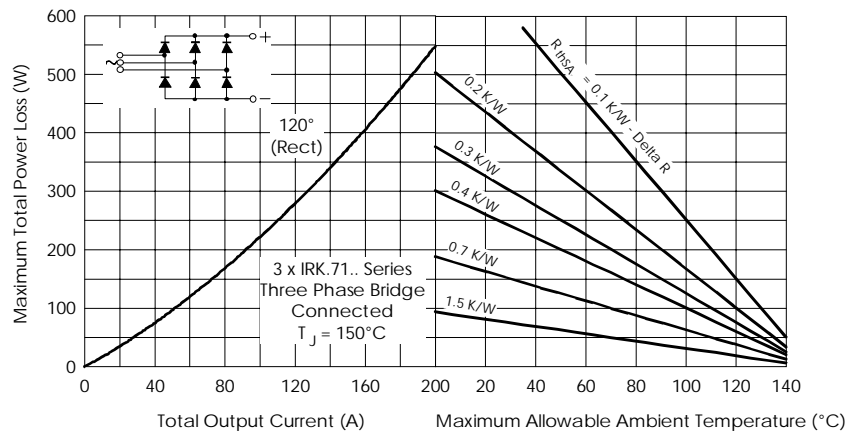


Fig. 18 - Forward Power Loss Characteristics



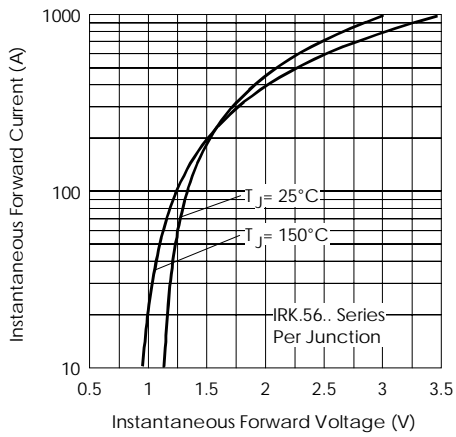


Fig. 19 - Forward Voltage Drop Characteristics

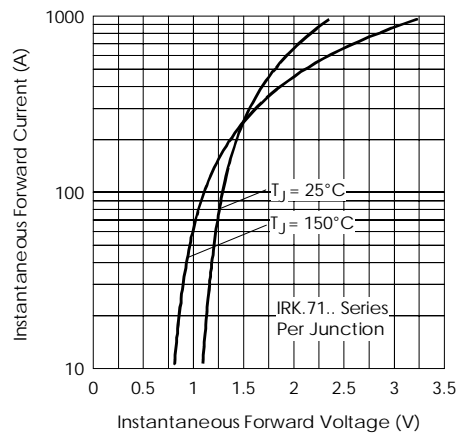


Fig. 20 - Forward Voltage Drop Characteristics

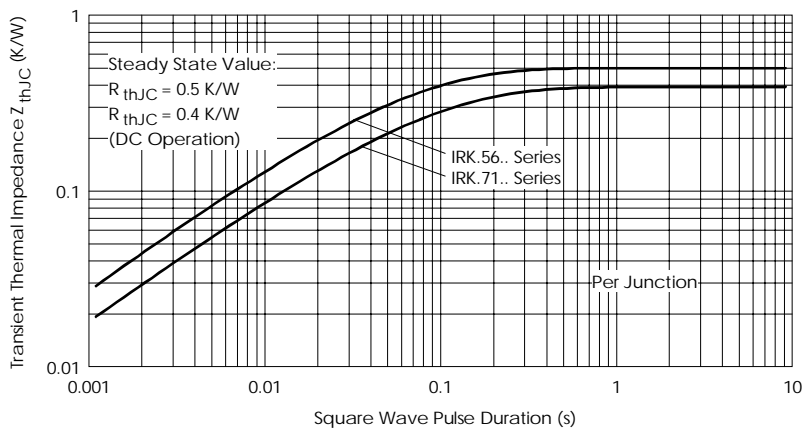


Fig. 21 - Thermal Impedance  $Z_{thJC}$  Characteristic

Data and specifications subject to change without notice.  
 This product has been designed and qualified for Industrial Level.  
 Qualification Standards can be found on IR's Web site.